Features

- Integrated PLL Loop Filter
- ESD Protection (4 kV HBM/ 200 V MM; Except Pin 2: 4 kV HBM/ 100 V MM) also at ANT1/ANT2
- High Output Power (8.0 dBm) with Low Supply Current (9.0 mA)
- Modulation Scheme ASK/FSK
  - FSK Modulation is Achieved by Connecting an Additional Capacitor Between the XTAL Load Capacitor and the Open Drain Output of the Modulating Microcontroller
- Easy to Design-in Due to Excellent Isolation of the PLL from the PA and Power Supply
- Single Li-cell for Power Supply
- Supply Voltage 2.0 V to 4.0 V in the Temperature Range of -40° C to 85° C/125° C
- Package TSSOP8L
- Single-ended Antenna Output with High Efficient Power Amplifier
- CLK Output for Clocking the Microcontroller
- One-chip Solution with Minimum External Circuitry
- 125° C Operation for Tire Pressure Systems

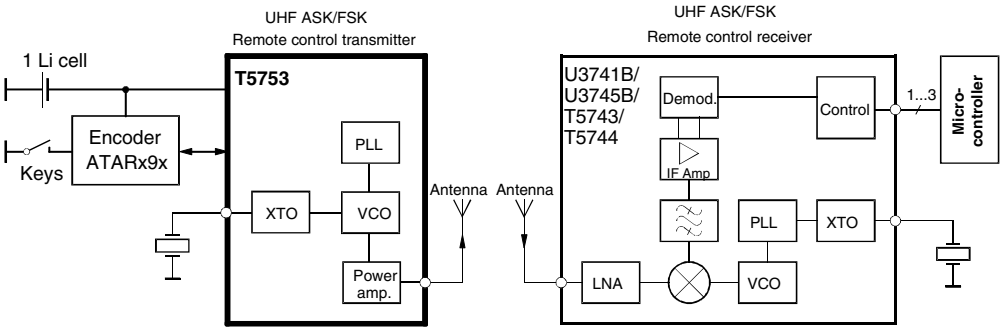
UHF ASK/FSK Transmitter

T5753

Description

The T5753 is a PLL transmitter IC which has been developed for the demands of RF low-cost transmission systems at data rates up to 32 kBaud. The transmitting frequency range is 310 MHz to 330 MHz. It can be used in both FSK and ASK systems.

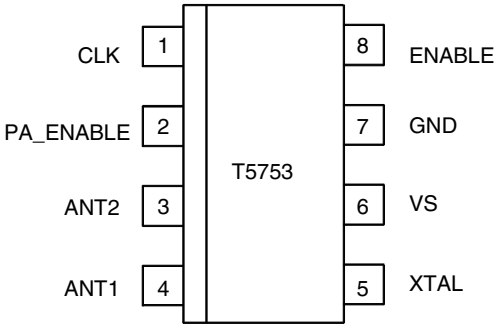
Figure 1. System Block Diagram



Rev. 4510F–RKE–07/04

Pin Configuration

Figure 2. Pinning TSSOP8L



Pin Description

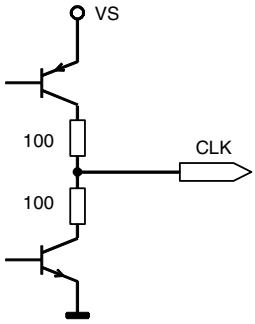
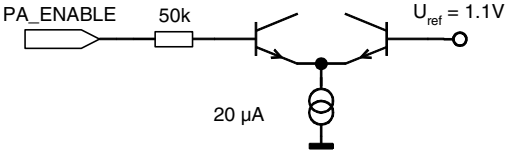
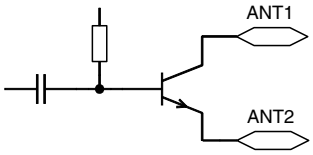
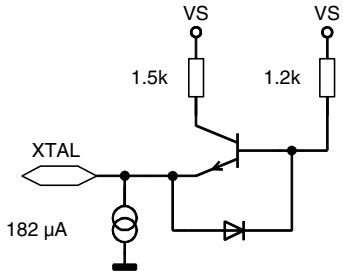
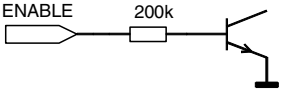
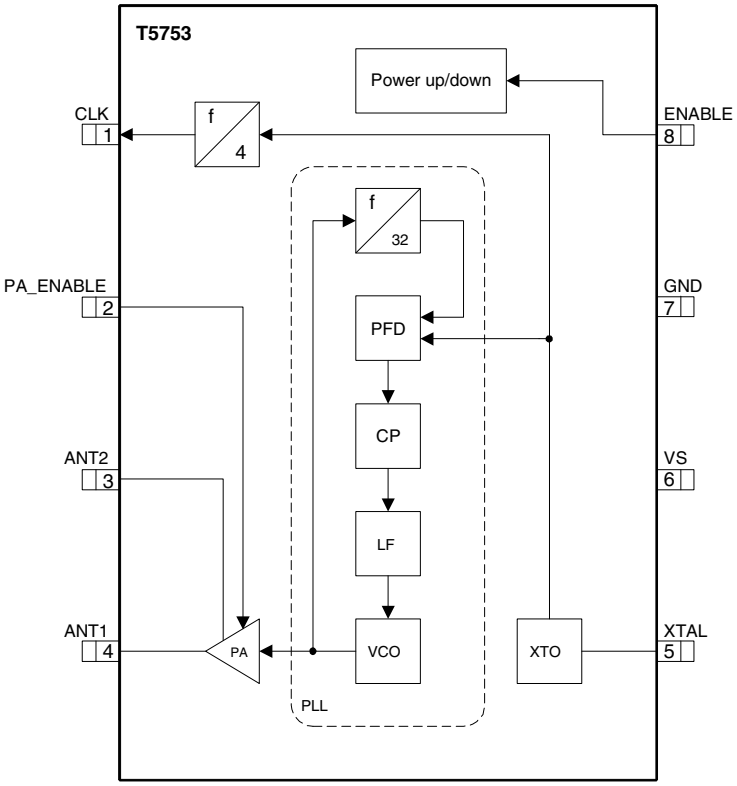
Pin	Symbol	Function	Configuration
1	CLK	Clock output signal for microcontroller The clock output frequency is set by the crystal to $f_{XTAL}/4$	
2	PA_ENABLE	Switches on power amplifier, used for ASK modulation	
3 4	ANT2 ANT1	Emitter of antenna output stage Open collector antenna output	
5	XTAL	Connection for crystal	
6	VS	Supply voltage	See ESD protection circuitry (see Figure 8 on page 8)
7	GND	Ground	See ESD protection circuitry (see Figure 8 on page 8)
8	ENABLE	Enable input	

Figure 3. Block Diagram



General Description

This fully integrated PLL transmitter allows particularly simple, low-cost RF miniature transmitters to be assembled. The VCO is locked to 32 f_{XTAL} hence a 9.8438 MHz crystal is needed for a 315 MHz transmitter. All other PLL and VCO peripheral elements are integrated.

The XTO is a series resonance oscillator so that only one capacitor together with a crystal connected in series to GND are needed as external elements.

The crystal oscillator together with the PLL needs typically < 3 ms until the PLL is locked and the CLK output is stable. There is a wait time of ≥ 3 ms until the CLK is used for the microcontroller and the PA is switched on.

The power amplifier is an open-collector output delivering a current pulse which is nearly independent from the load impedance. The delivered output power is hence controllable via the connected load impedance.

This output configuration enables a simple matching to any kind of antenna or to 50 Ω. A high power efficiency of $\eta = P_{out}/(I_{S,PA} \ V_S)$ of 40% for the power amplifier results when an optimized load impedance of Z_{Load} = (255 + j192) Ω is used at 3 V supply voltage.

Functional Description

If ENABLE = L and the PA_ENABLE = L, the circuit is in standby mode consuming only a very small amount of current so that a lithium cell used as power supply can work for several years.

With ENABLE = H the XTO, PLL and the CLK driver are switched on. If PA_ENABLE remains L only the PLL and the XTO is running and the CLK signal is delivered to the microcontroller. The VCO locks to 32 times the XTO frequency.

With ENABLE = H and PA_ENABLE = H the PLL, XTO, CLK driver and the power amplifier are on. With PA_ENABLE the power amplifier can be switched on and off, which is used to perform the ASK modulation.

ASK Transmission

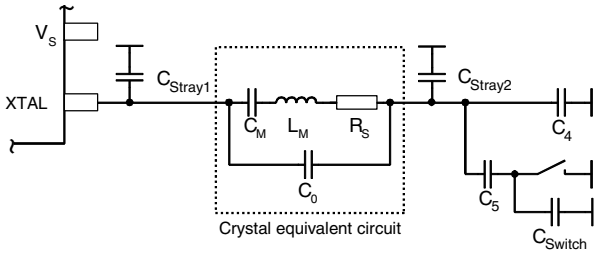
The T5753 is activated by ENABLE = H. PA_ENABLE must remain L for typically ≥ 3 ms, then the CLK signal can be taken to clock the microcontroller and the output power can be modulated by means of Pin PA_ENABLE. After transmission PA_ENABLE is switched to L and the microcontroller switches back to internal clocking. The T5753 is switched back to standby mode with ENABLE = L.

FSK Transmission

The T5753 is activated by ENABLE = H. PA_ENABLE must remain L for typically ≥ 3 ms, then the CLK signal can be taken to clock the microcontroller and the power amplifier is switched on with PA_ENABLE = H. The chip is then ready for FSK modulation. The microcontroller starts to switch on and off the capacitor between the XTAL load capacitor and GND with an open-drain output port, thus changing the reference frequency of the PLL. If the switch is closed, the output frequency is lower than if the switch is open. After transmission PA_ENABLE is switched to L and the microcontroller switches back to internal clocking. The T5753 is switched back to standby mode with ENABLE = L.

The accuracy of the frequency deviation with XTAL pulling method is about ±25% when the following tolerances are considered.

Figure 4. Tolerances of Frequency Modulation



Using C_4 = 8.2 pF ± 5%, C_5 = 10 pF ± 5%, a switch port with C_{Switch} = 3 pF ± 10%, stray capacitances on each side of the crystal of $C_{Stray1} = C_{Stray2}$ = 1 pF ± 10%, a parallel capacitance of the crystal of C_0 = 3.2 pF ± 10% and a crystal with C_M = 13 fF ± 10%, an FSK deviation of ±21.5 kHz typical with worst case tolerances of ±16.25 kHz to ±28.01 kHz results.

CLK Output

An output CLK signal is provided for a connected microcontroller, the delivered signal is CMOS compatible if the load capacitance is lower than 10 pF.

Clock Pulse Take-over

The clock of the crystal oscillator can be used for clocking the microcontroller. Atmel's ATARx9x has the special feature of starting with an integrated RC-oscillator to switch on the T5753 with ENABLE = H, and after 1 ms to assume the clock signal of the transmission IC, so that the message can be sent with crystal accuracy.

Output Matching and Power Setting

The output power is set by the load impedance of the antenna. The maximum output power is achieved with a load impedance of $Z_{Load,opt}$ = (255 + j192) Ω. There must be a low resistive path to V_S to deliver the DC current.

The delivered current pulse of the power amplifier is 9 mA and the maximum output power is delivered to a resistive load of 400 Ω if the 1.0 pF output capacitance of the power amplifier is compensated by the load impedance.

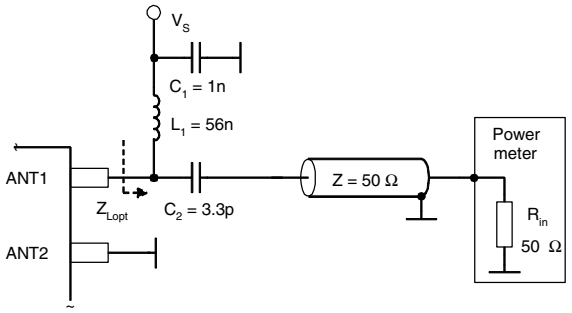
An optimum load impedance of:
Z_{Load} = 400 Ω || j/(2 × π 1.0 pF) = (255 + j192) Ω thus results for the maximum output power of 8 dBm.

The load impedance is defined as the impedance seen from the T5753's ANT1, ANT2 into the matching network. Do not confuse this large signal load impedance with a small signal input impedance delivered as input characteristic of RF amplifiers and measured from the application into the IC instead of from the IC into the application for a power amplifier.

Less output power is achieved by lowering the real parallel part of 400 Ω where the parallel imaginary part should be kept constant.

Output power measurement can be done with the circuit of Figure 5. Note that the component values must be changed to compensate the individual board parasitics until the T5753 has the right load impedance $Z_{Load,opt}$ = (255 + j192) Ω. Also the damping of the cable used to measure the output power must be calibrated out.

Figure 5. Output Power Measurement



Application Circuit

For the blocking of the supply voltage a capacitor value of C_3 = 68 nF/X7R is recommended (see Figure 6 on page 6 and Figure 7 on page 7). C_1 and C_2 are used to match the loop antenna to the power amplifier where C_1 typically is 22 pF/NP0 and C_2 is 10.8 pF/NP0 (18 pF + 27 pF in series); for C_2 two capacitors in series should be used to achieve a better tolerance value and to have the possibility to realize the $Z_{Load,opt}$ by using standard valued capacitors.

C_1 forms together with the pins of T5753 and the PCB board wires a series resonance loop that suppresses the 1st harmonic, hence the position of C_1 on the PCB is important. Normally the best suppression is achieved when C_1 is placed as close as possible to the pins ANT1 and ANT2.

The loop antenna should not exceed a width of 1.5 mm, otherwise the Q-factor of the loop antenna is too high.

L_1 ([50 nH to 100 nH) can be printed on PCB. C_4 should be selected that the XTO runs on the load resonance frequency of the crystal. Normally, a value of 12 pF results for a 15 pF load-capacitance crystal.

Figure 6. ASK Application Circuit

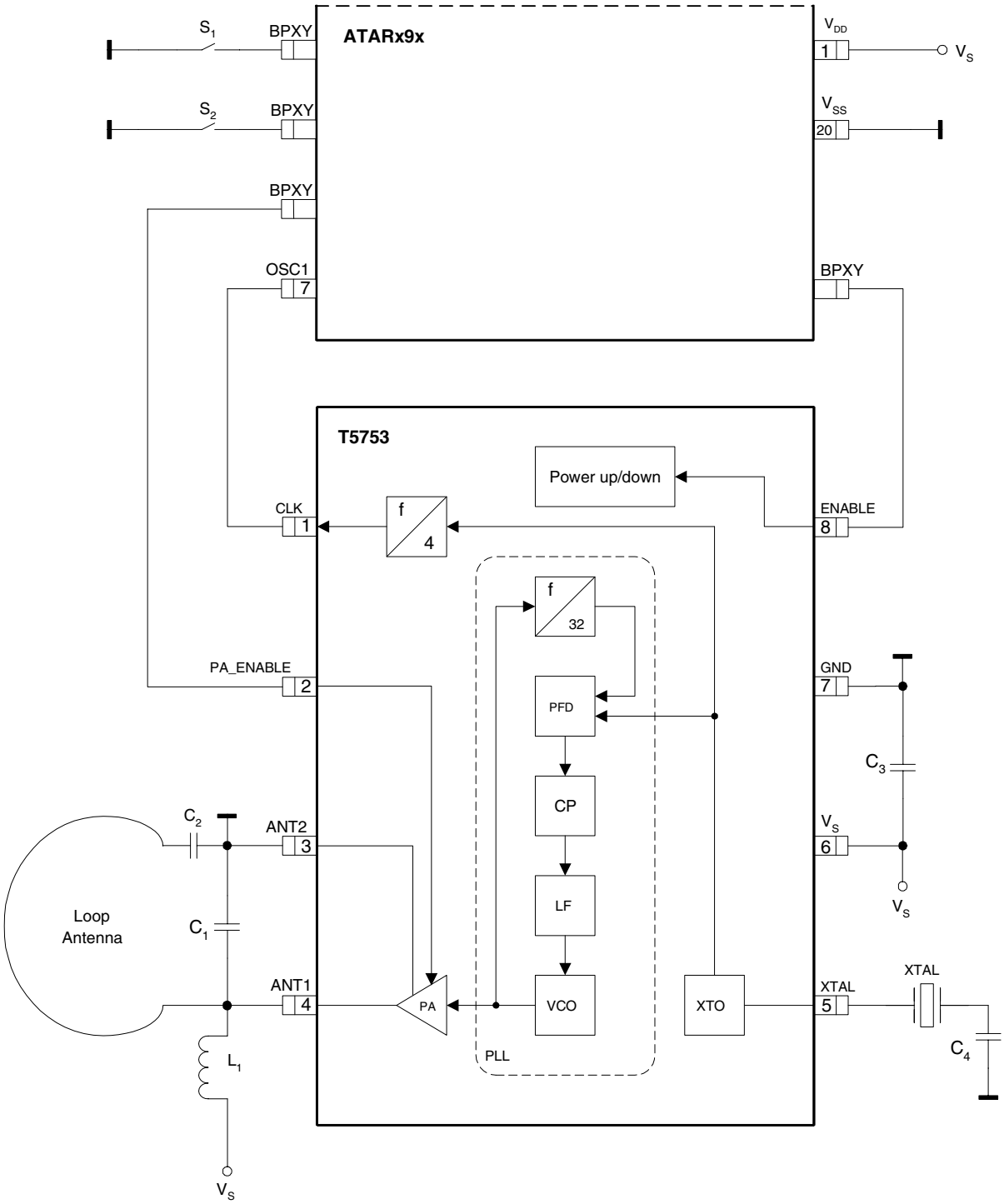


Figure 7. FSK Application Circuit

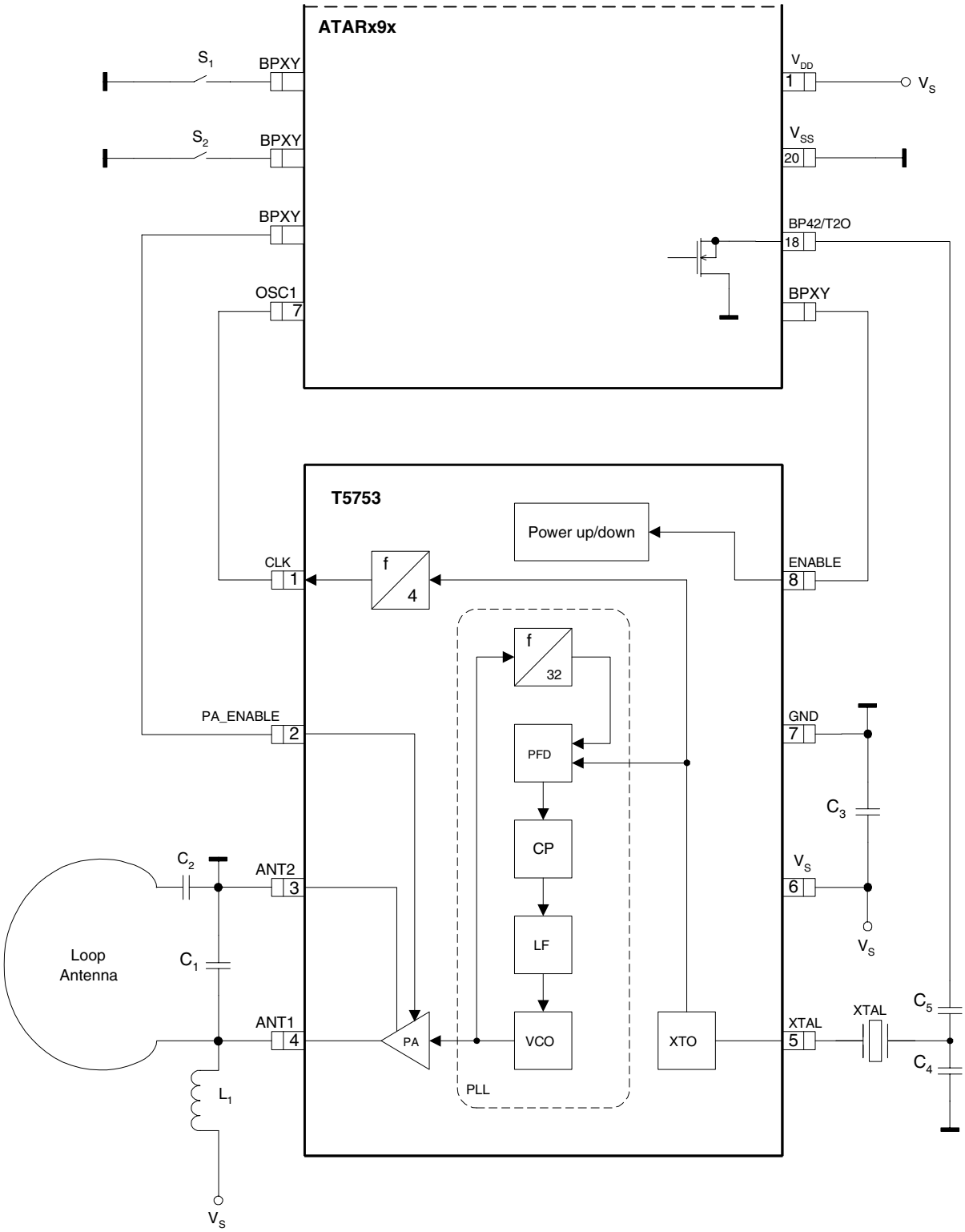
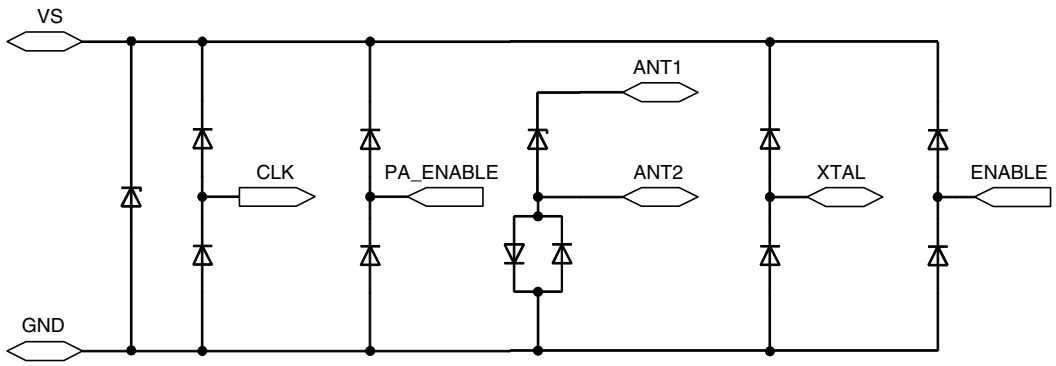


Figure 8. ESD Protection Circuit



Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Symbol	Minimum	Maximum	Unit
Supply voltage	V_S		5	V
Power dissipation	P_{tot}		100	mW
Junction temperature	T_j		150	°C
Storage temperature	T_{stg}	-55	125	°C
Ambient temperature	T_{amb}	-55	125	°C
Input voltage	V_{maxPA_ENABLE}	-0.3	$(V_S + 0.3)^{(1)}$	V

Note: 1. If V_S + 0.3 is higher than 3.7 V, the maximum voltage will be reduced to 3.7 V.

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R_{thJA}	170	K/W

Electrical Characteristics

V_S = 2.0 V to 4.0 V, T_{amb} = -40° C to 125° C unless otherwise specified.
Typical values are given at V_S = 3.0 V and T_{amb} = 25° C. All parameters are referred to GND (pin 7).

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Supply current	Power down, V_{ENABLE} < 0.25 V, -40° C to 85° C $V_{PA-ENABLE}$ < 0.25 V, -40°C to +125° C $V_{PA-ENABLE}$ < 0.25 V, 25°C (100% correlation tested)	I_{S_Off}		 <10	350 7 	nA µA nA
Supply current	Power up, PA off, V_S = 3 V, V_{ENABLE} > 1.7 V, $V_{PA-ENABLE}$ < 0.25 V	I_S		3.7	4.8	mA
Supply current	Power up, V_S = 3.0 V, V_{ENABLE} > 1.7 V, $V_{PA-ENABLE}$ > 1.7 V	$I_{S\_Transmit}$		9	11.6	mA
Output power	V_S = 3.0 V, T_{amb} = 25° C, f = 315 MHz, Z_{Load} = (255 + j192) W	P_{Ref}	6.0	8.0	10.5	dBm
Output power variation for the full temperature range	T_{amb} = -40° C to +85° C, V_S = 3.0 V V_S = 2.0 V	 ΔP_{Ref} ΔP_{Ref}			 -1.5 -4.0	 dB dB
Output power variation for the full temperature range	T_{amb} = -40°C to +125°C, V_S = 3.0 V V_S = 2.0 V, $P_{Out} = P_{Ref} + \Delta P_{Ref}$	 ΔP_{Ref} ΔP_{Ref}			 -2.0 -4.5	 dB dB
Achievable output-power range	Selectable by load impedance	P_{Out_typ}	0		8.0	dBm
Spurious emission	$f_{CLK} = f_0/128$ Load capacitance at Pin CLK = 10 pF $f_O \pm 1 \times f_{CLK}$ $f_O \pm 4 \times f_{CLK}$ other spurious are lower			 -55 -52		 dBc dBc
Oscillator frequency XTO (= phase comparator frequency)	$f_{XTO} = f_0/32$ f_{XTAL} = resonant frequency of the XTAL, $C_M \leq$10 fF, load capacitance selected accordingly T_{amb} = -40° C to +85° C, T_{amb} = -40° C to +125° C	f_{XTO}	 -30 -40	 f_{XTAL}	 +30 +40	 ppm ppm
PLL loop bandwidth				250		kHz
Phase noise of phase comparator	Referred to $f_{PC} = f_{XT0}$, 25 kHz distance to carrier			-116	-110	dBc/Hz
In loop phase noise PLL	25 kHz distance to carrier			-86	-80	dBc/Hz
Phase noise VCO	at 1 MHz at 36 MHz			-94 -125	-90 -121	dBc/Hz dBc/Hz
Frequency range of VCO		f_{VCO}	310		330	MHz
Clock output frequency (CMOS microcontroller compatible)				$f_0/128$		MHz
Voltage swing at Pin CLK	$C_{Load} \leq$10 pF	V_{0h} V_{0l}	$V_S \times 0.8$		$V_S \times 0.2$	V V
Series resonance R of the crystal		Rs			110	Ω
Capacitive load at Pin XT0					7	pF

Note: 1. If V_S is higher than 3.6 V, the maximum voltage will be reduced to 3.6 V.

Electrical Characteristics (Continued)

V_S = 2.0 V to 4.0 V, T_{amb} = -40° C to 125° C unless otherwise specified.
Typical values are given at V_S = 3.0 V and T_{amb} = 25° C. All parameters are referred to GND (pin 7).

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
FSK modulation frequency rate	Duty cycle of the modulation signal = 50%		0		32	kHz
ASK modulation frequency rate	Duty cycle of the modulation signal = 50%		0		32	kHz
ENABLE input	Low level input voltage High level input voltage Input current high	V_{Il} V_{Ih} I_{In}	 1.7		0.25 20	V V µA
PA_ENABLE input	Low level input voltage High level input voltage Input current high	V_{Il} V_{Ih} I_{In}	 1.7		0.25 V_S (1) 5	V V µA

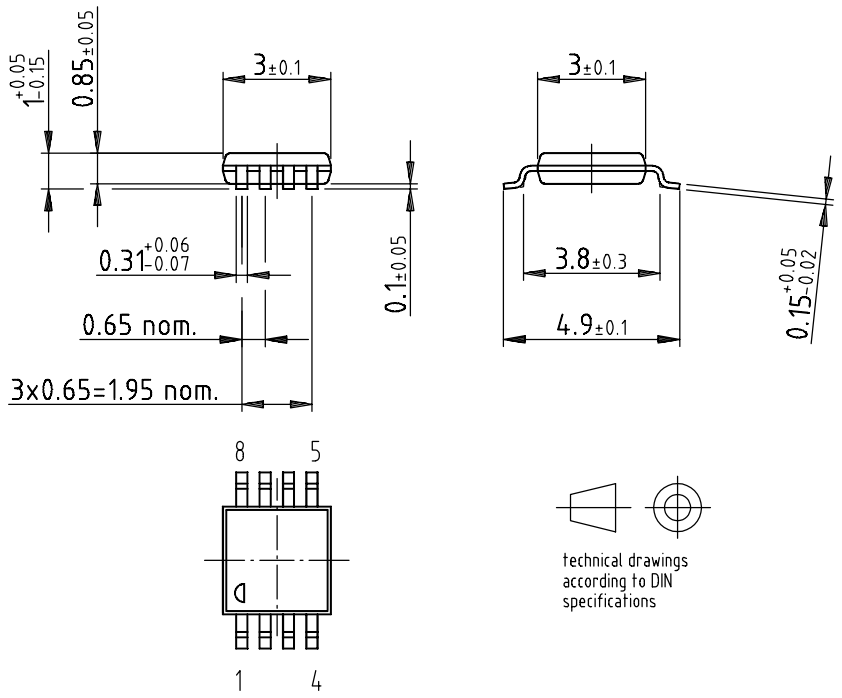
Note: 1. If V_S is higher than 3.6 V, the maximum voltage will be reduced to 3.6 V.

Ordering Information

Extended Type Number	Package	Remarks
T5753-6AQ	TSSOP8L	Taped and reeled, Marking: T573

Package Information

Package: TSSOP 8L
Dimensions in mm



Drawing-No.: 6.543-5083.01-4
Issue: 1; 08.01.02

Revision History

Please note that the following page numbers referred to in this section refer to the specific revision mentioned, not to this document.

Changes from Rev. 4510E-RKE-10/03 to Rev. 4510F-RKE-07/04

1. Abs. Max. Ratings table (page 8): row “Input voltage” added
2. Abs. Max. Ratings table (page 8): table note 1 added
3. El. Char. table (page 10): row “PA_ENABLE input“ changed
4. El. Char. table (page 10): table note 1 added
5. Ordering Information table (page 11): Remarks changed

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